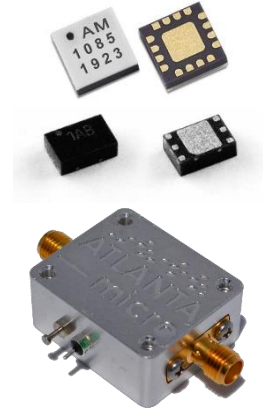


AM1085 – Amplifier

DC to 6 GHz Gain Block

Description

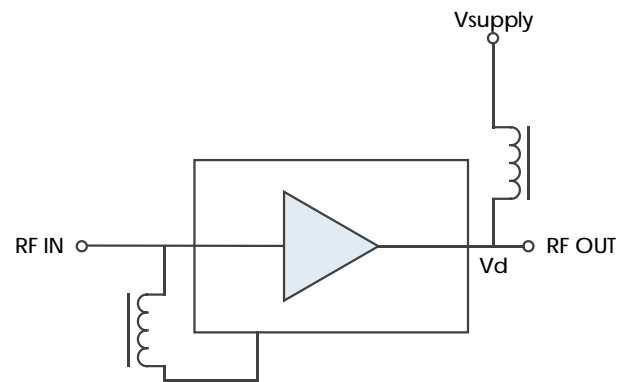
The AM1085 is a DC-coupled amplifier covering up to 6 GHz. The device exhibits a moderate positive gain slope, providing frequency equalization useful in many broadband applications. With internal 50Ω matching and packaged in a 3mm QFN, 1.3mm x 2mm DFN, or a shielded module, the AM1085 represents a compact total PCB footprint.



Features

- 16 dB Gain
- 2.5 dB Noise Figure
- +35 dBm OIP3
- +20 dBm P1dB
- +5.0V Operation
- 3mm QFN
- -40C to +85C Operation

Functional Diagram



Characteristic Performance

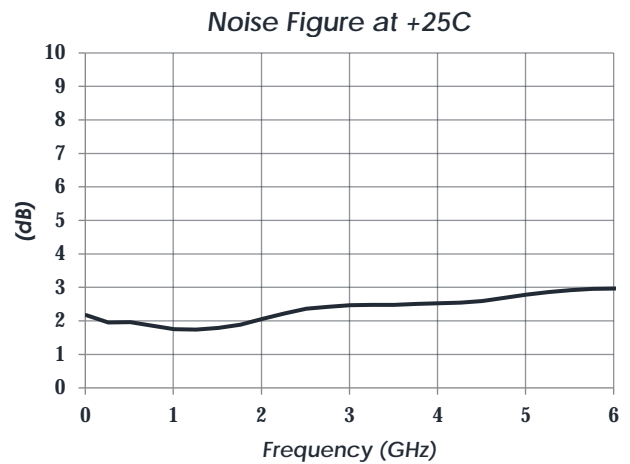
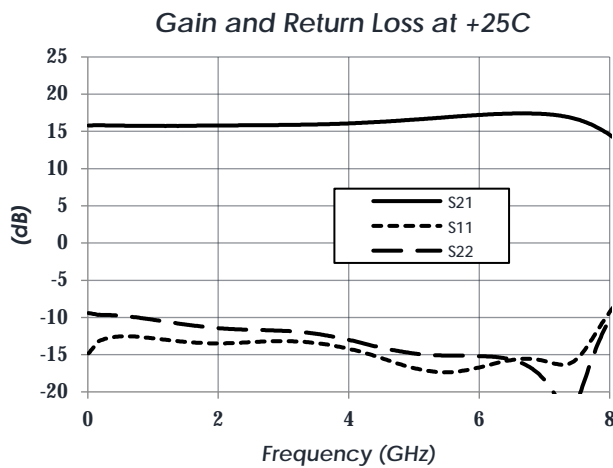


Table of Contents

Description	1	Recommended Operating Conditions ...	5
Features	1	Thermal Information	5
Functional Diagram	1	DC Electrical Characteristics	6
Characteristic Performance	1	RF Performance	6
Revision History	2	Typical Performance	7
Pin Layout and Definitions	3	Typical Application	9
AM1085-1: 3mm QFN	3	Part Ordering Details	10
AM1085-2: 1.3mm x 2mm DFN	4	Related Parts	10
Specifications	5	Evaluation PC Board	10
Absolute Maximum Ratings	5	Component Compliance Information	11
Handling Information	5		

Revision History

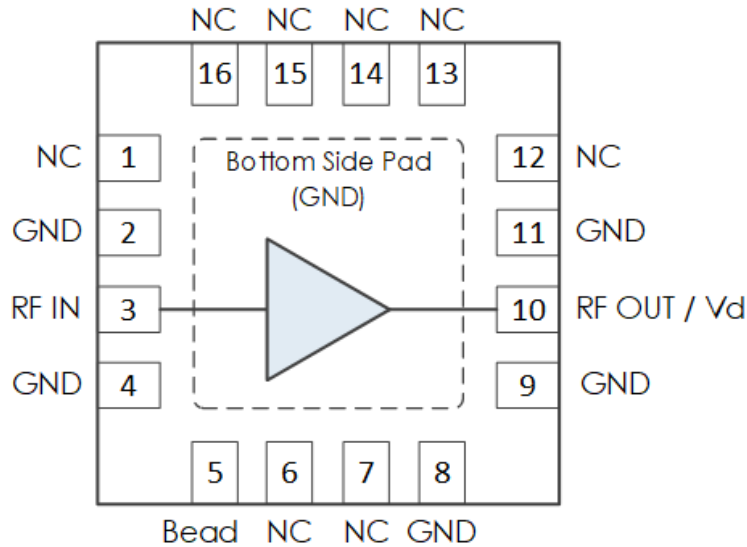
Date	Revision Number	Notes
July 23, 2019	1	Initial Release
November 26, 2019	1A	Updated Description to include shielded module packaging
November 11, 2020	2	Package and Module information moved to main product page on website.

AM1085 – Amplifier

DC to 6 GHz Gain Block

Pin Layout and Definitions

AM1085-1: 3mm QFN



Pin Number	Pin Name	Pin Function
1	NC	Not Connected*
2	GND	Ground - Common
3	RF In	RF Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
4	GND	Ground - Common
5	Bead	Connect to RF In through external ferrite bead or large inductor
6,7	NC	Not Connected*
8,9	GND	Ground - Common
10	RF Out / Vd	RF Output – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
11	GND	Ground - Common
12-16	NC	Not Connected*

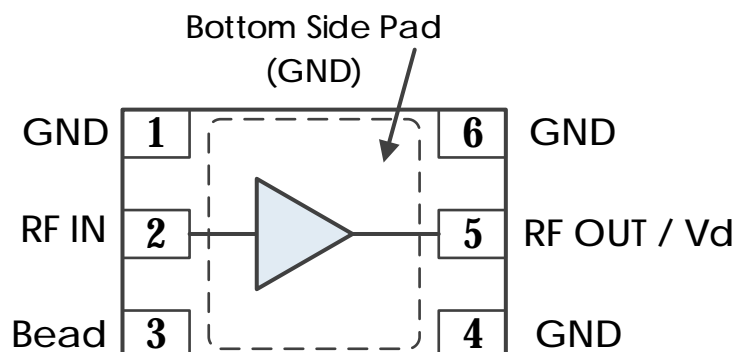
*NC pins may be grounded or left open

AM1085 – Amplifier

DC to 6 GHz Gain Block

Pin Layout and Definitions (Continued)

AM1085-2: 1.3mm x 2mm DFN



Pin Number	Pin Name	Pin Function
1	GND	Ground – Common
2	RF In	RF Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
3	Bead	Connect to RF In through external ferrite bead or large inductor
4	GND	Ground – Common
5	RF Out	RF Output – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
6	GND	Ground – Common

AM1085 – Amplifier

DC to 6 GHz Gain Block

Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	-0.3 V	+9.0V
RF Input Power		+20dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.
Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+4.5 V	+5.0 V	+5.5 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ_{JC})	38.5

AM1085 – Amplifier

DC to 6 GHz Gain Block

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
DC Supply Voltage			+5.0 V	
DC Supply Current	V Supply = +5.0 V		79 mA	
Power Dissipated	V Supply = +5.0 V		0.4 W	

RF Performance

(T = 25 °C unless otherwise specified)

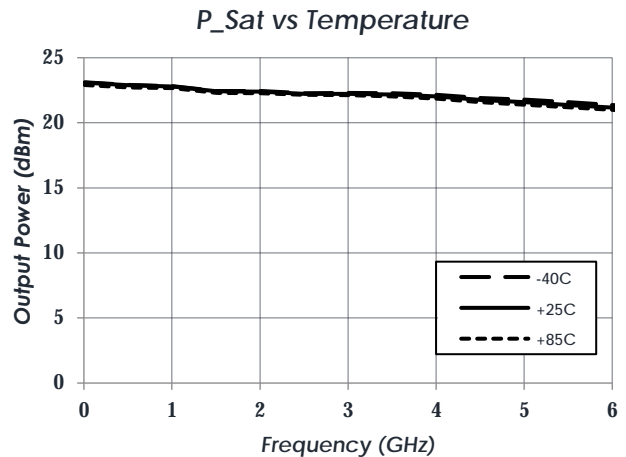
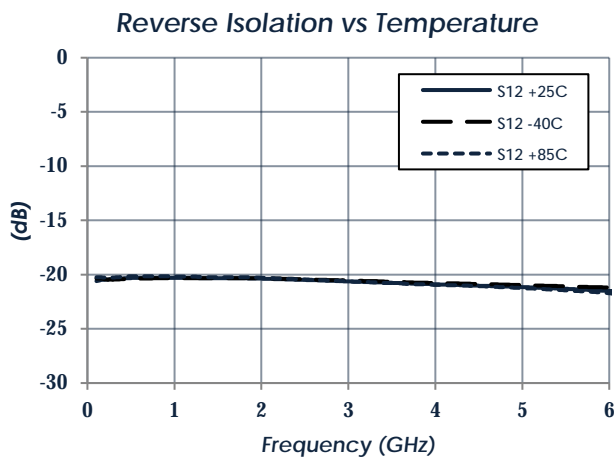
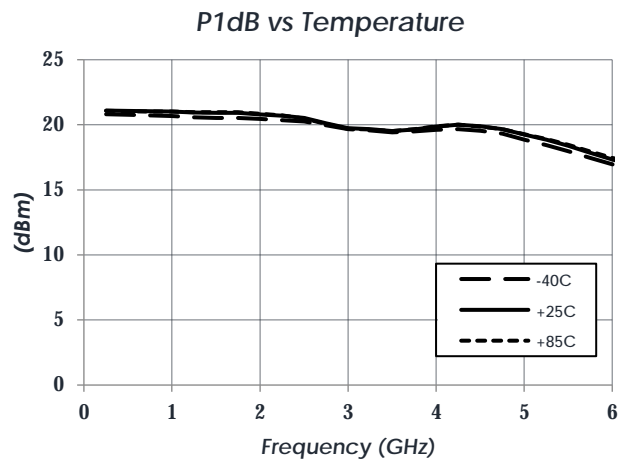
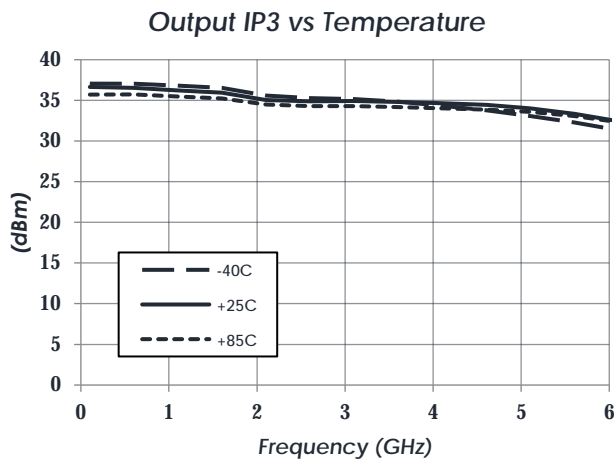
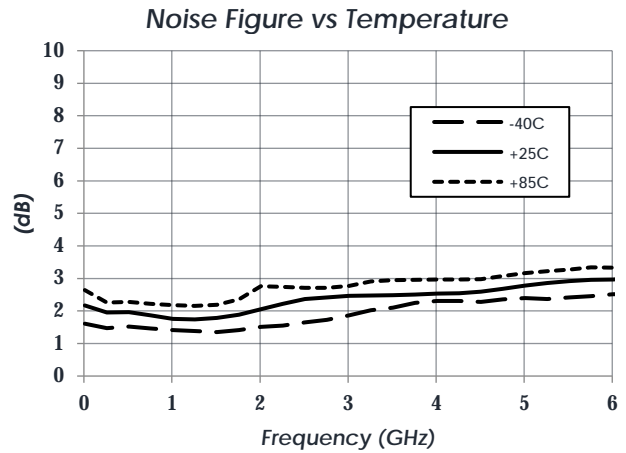
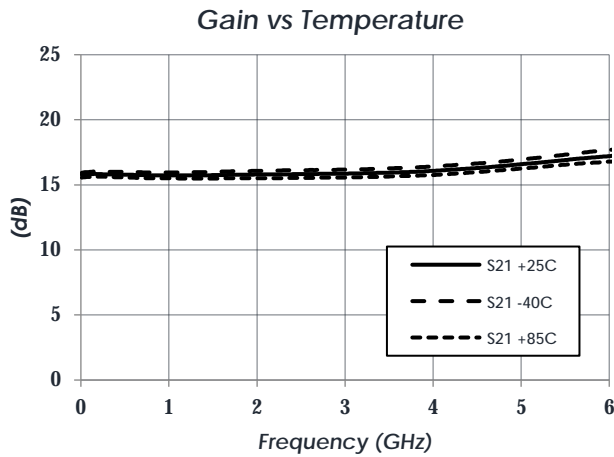
Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		DC		6 GHz
Gain	V Supply = +5.0 V		16 dB	
Return Loss	V Supply = +5.0 V		12 dB	
Output IP3			35 dBm	
Output P1dB			20 dBm	
Noise Figure			2.5 dB	

AM1085 – Amplifier

DC to 6 GHz Gain Block

Typical Performance

(Vd = +5.0 V, Id = 79 mA)



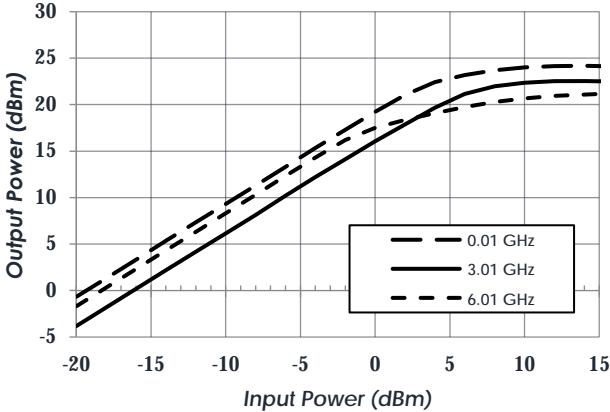
AM1085 – Amplifier

DC to 6 GHz Gain Block

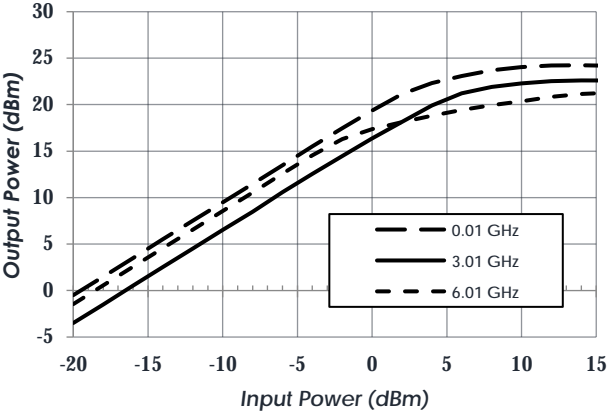
Typical Performance (continued)

(Vd = +5.0 V, Id = 79 mA)

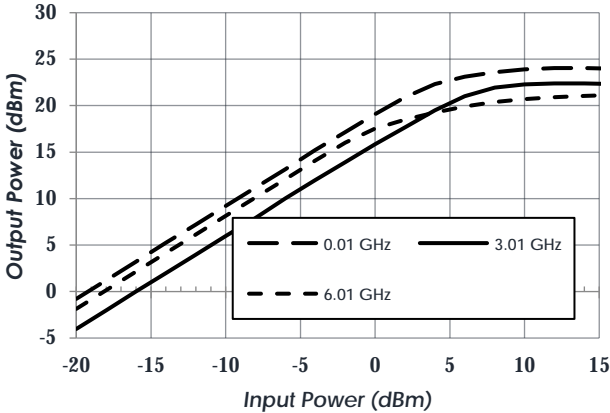
Pin vs. Pout at +25C



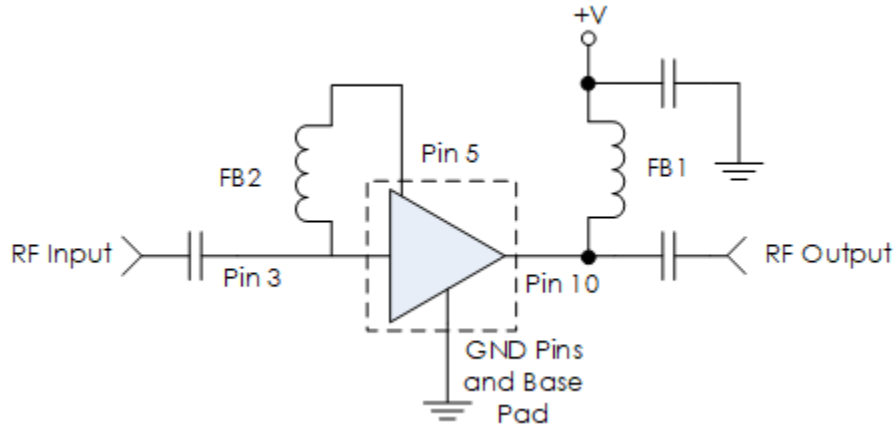
Pin vs. Pout at -40C



Pin vs. Pout at +85C



Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 μ F	0402BB104KW160	Passives Plus
C3	0.1 μ F	GRM155R71C104KA88	Murata
FB1, FB2	-	MMZ1005A222E	TDK

Notes:

1. NC pins may be grounded or left open
2. DC blocking capacitors should be high performance, low-loss, broadband capacitors for optimum performance

AM1085 – Amplifier

DC to 6 GHz Gain Block

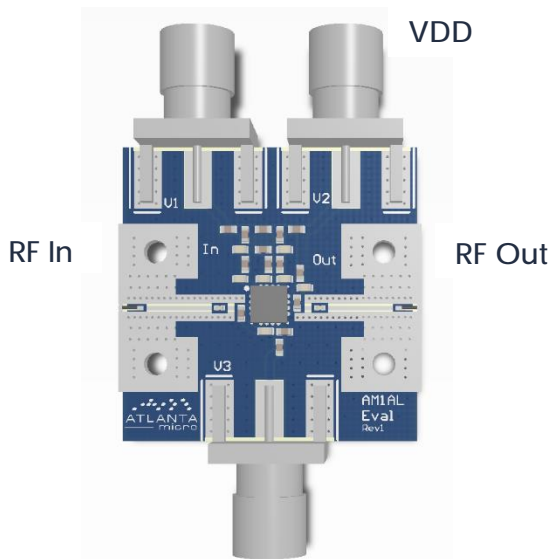
Part Ordering Details

Description	Part Number
3mm 16 Lead QFN	AM1085-1
1.3mm x 2mm 6 Lead DFN	AM1085-2
AM1085-1 Evaluation Board	AM1085-1 Eval
AM1085-2 Evaluation Board	AM1085-2 Eval
AM1085 in 0.95" x 1.13" x 0.6" RF-Shielded Module with Integrated Bias Tee and Field Replaceable SMA Connectors	AM1085-M

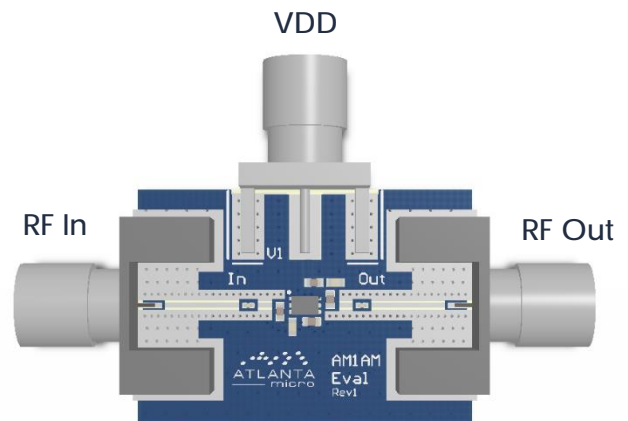
Related Parts

Part Number	Description
AM1016B	20 MHz to 6 GHz +3.3V Gain Block
AM1018C	20 MHz to 6 GHz +5.0V Gain Block
AM1025B	20 MHz to 3 GHz +8.0V Gain Block (High P1dB)
AM1031C	20 MHz to 8 GHz +3.3V Gain Block
AM1063-1	DC to 10 GHz Gain Block
AM1064-1	DC to 8 GHz Gain Block
AM1065	DC to 8 GHz Bypassable Gain Block
AM1073	DC to 8 GHz Bidirectional / Bypassable Gain Block
AM1084	DC to 6 GHz +3.3V or +5.0V Gain Block
AM1090	DC to 6 GHz +5.0V or +8.0V Gain Block

Evaluation PC Board



AM1085-1 Eval



AM1085-2 Eval

To obtain price, delivery, or to place an order contact MMICSales@mrcty.com
 Atlanta Micro Inc., 3720 Davinci Ct, Suite 125, Norcross, GA 30092 • Phone: (470) 253-7640 • www.atlantamicro.com

Component Compliance Information

RoHS: Atlanta Micro, Inc. hereby certifies that all products comply with the EC Directive 2011/65/EC on the Restriction of Hazardous Substances, commonly known as EU-RoHS 6 and 10. All products supplied by Atlanta Micro shall be compliant with the European Directive 2011/65/EC based on the following substance list.

Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

REACH: Atlanta Micro, Inc. neither uses nor intentionally adds any of the substances considered to be a Substance of Very High Concern (SVHC) as defined by the EU Regulation (EC) No. 1907-2006 on Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH).

Conflict Materials: Atlanta Micro does not knowingly use materials that are sourced from the Democratic Republic of Congo (DRC) or any other known conflict regions. Atlanta Micro’s supply chain is comprised of sources that are both environmentally and socially responsible. We periodically review this requirement with our vendors to ensure continued compliance.

Atlanta Micro takes its responsibility as a global partner seriously and will use due diligence within our supply chain to ensure all standards are met to the best of our knowledge.